

## 600V 6A N-Channel Enhancement Mode Power MOSFET

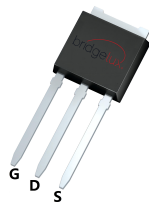
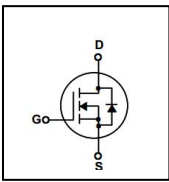
### General Description

BXP6N60 is Bridgelux high voltage MOSFET family based on advanced planar stripe DMOS technology. This advanced MOSFET family has optimized on-state resistance, and also provides superior switching performance and higher avalanche energy strength. This device family is suitable for high efficiency switch mode power supplies.

### FEATURES

- $R_{DS(ON)} \leq 1.7 \Omega$  @  $V_{GS}=10V, I_D=3A$
- Excellent  $R_{DS(ON)}$  and Low Gate Charge
- Fast switching capability
- Lead free product is acquired

### SYMBOL



TO-251L



TO-252



TO-220



TO-220F

### ASSEMBLY MESSAGE

Product Name	Marking	Package	Packaging
BXP6N60U	BXP6N60U	TO-251L	Tube
BXP6N60D	BXP6N60D	TO-252	Tube/Reel
BXP6N60P	BXP6N60P	TO-220	Tube
BXP6N60F	BXP6N60F	TO-220F	Tube

### ABSOLUTE MAXIMUM RATINGS ( $T_C=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Rating			Unit
		BXP6N60U/D	BXP6N60P	BXP6N60F	
Drain-Source Voltage	$V_{DSS}$	600			V
Drain Current	Continuous ( $T_C = 25^\circ\text{C}$ )	6			A
	Continuous ( $T_C = 100^\circ\text{C}$ )	3.5			A
Drain Current	Pulsed (Note1)	24			A
Gate-Source Voltage	$V_{GSS}$	$\pm 30$			V
Avalanche Energy	Single Pulse (Note2)	350			mJ
	Repetitive (Note1)	38			mJ
Avalanche Current (Note1)	$I_{AR}$	6			A
Peak Diode Recovery dv/dt (Note3)	dv/dt	5			V/ns
Power Dissipation (Note 2)	$T_C = 25^\circ\text{C}$	85	100	39	W
	Derate above $25^\circ\text{C}$	0.68	0.8	0.31	W/ $^\circ\text{C}$
Maximum Junction Temperature	$T_J$	150			$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 to 150			$^\circ\text{C}$

- Note:
1. Repetitive Rating: Pulse width limited by maximum junction temperature
  2.  $L=19.4\text{mH}$ ,  $I_{AS}=6.0\text{A}$ ,  $V_{DD}=50\text{V}$ ,  $R_G=25 \Omega$ , Starting  $T_J = 25^\circ\text{C}$
  3.  $I_{SD} \leq 6.0\text{A}$ ,  $di/dt \leq 300\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$

**THERMAL CHARACTERISTICS**

Parameter	Symbol	Max.			Unit
		BXP6N60U/D	BXP6N60P	BXP6N60F	
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.47	1.15	3.2	°C / W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	110	62	120	°C / W

**ELECTRICAL CHARACTERISTICS** ( $T_J=25^\circ\text{C}$ , unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	600			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=600V, V_{GS}=0V$			1	$\mu A$
		$V_{DS}=480V, T_C = 125^\circ\text{C}$			100	$\mu A$
Gate-Body Leakage Current, Forward	$I_{GSS}$	$V_{GS}=30V$			100	nA
Gate-Body Leakage Current, Reverse		$V_{GS}=-30V$			-100	nA
Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D = 250 \mu A$		0.67		$V/^\circ\text{C}$
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	3		4	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3A$		1.4	1.7	$\Omega$
Forward Transconductance (Note4)	$g_{FS}$	$V_{DS} = 50V, I_D = 6A$		8		S
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{ISS}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHz}$		725		pF
Output Capacitance	$C_{OSS}$			78		pF
Reverse Transfer Capacitance	$C_{RSS}$			7.6		pF
<b>SWITCHING PARAMETERS</b>						
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DD}=300V, I_D=6A, V_{GS} = 10V, R_G=10\Omega$ (Note4,5)		9.7		ns
Turn-ON Rise Time	$t_R$			12		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			36		ns
Turn-OFF Fall-Time	$t_F$			17		ns
Total Gate Charge(Note5)	$Q_G$	$V_{DS} = 300V, V_{GS} = 10V, I_D = 6A$ (Note4,5)		20		nC
Gate Source Charge	$Q_{GS}$			4.1		nC
Gate Drain Charge	$Q_{GD}$			7.6		nC
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Drain-Source Diode Forward Voltage	$V_{SD}$	$I_S=6A, V_{GS}=0V$			1.4	V
Diode Continuous Forward Current	$I_S$				6	A
Pulsed Drain-Source Current	$I_{SM}$				24	A
Reverse Recovery Time	$t_{RR}$	$V_{GS} = 0V, I_{SD} = 6A$		220		ns
Reverse Recovery Charge	$Q_{RR}$	$di/dt=100A/\mu s$ (Note4,5)		1.2		$\mu C$

Note: 4. Pulse Test : Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$

5. Essentially independent of operating temperature

**TYPICAL CHARACTERISTICS**

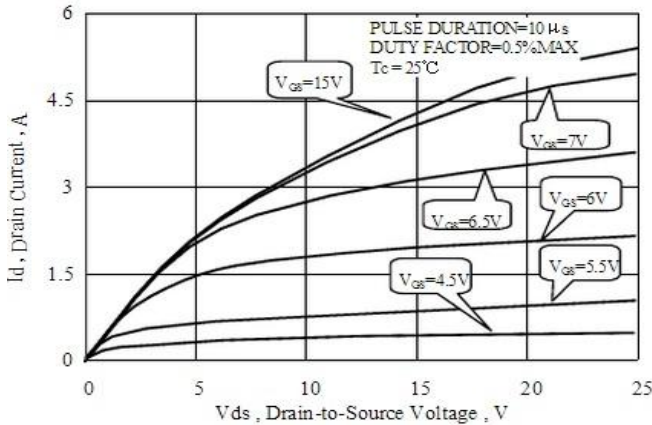


Figure 1. Typical Output Characteristics

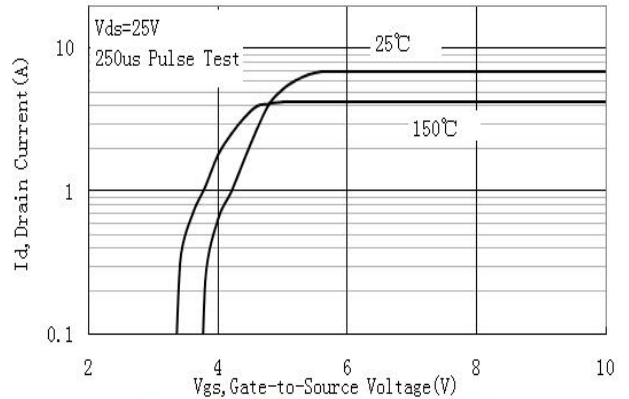


Figure 2. Typical Transfer Characteristics

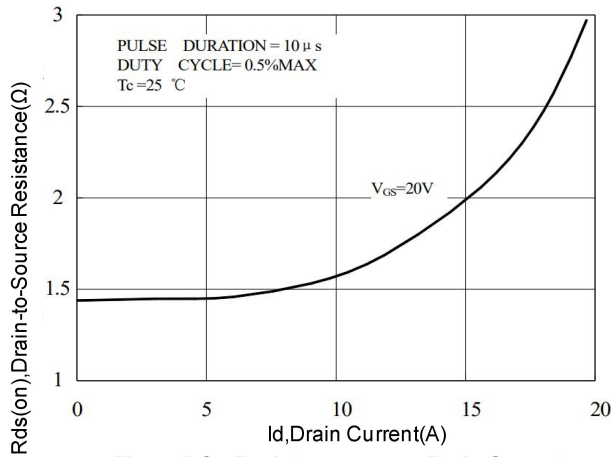


Figure 3. On-Resistance versus Drain Current

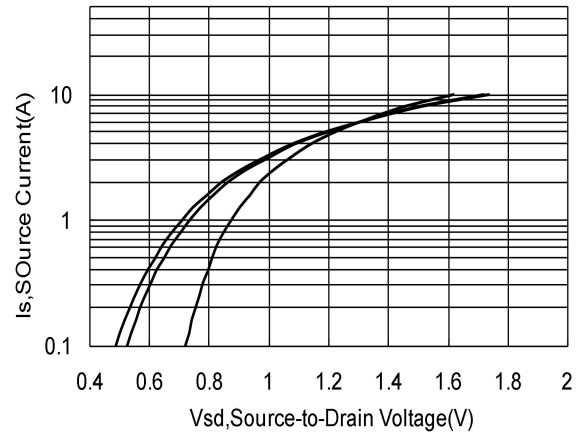


Figure 4. Diode Forward Voltage versus Current

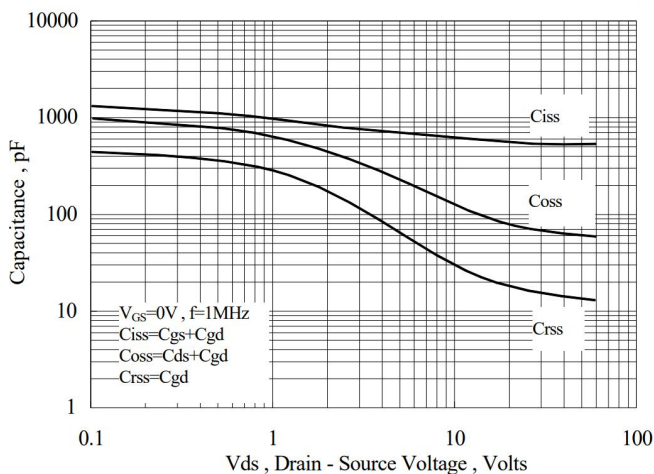


Figure 5. Typical Capacitance vs. Drain-to-Source Voltage

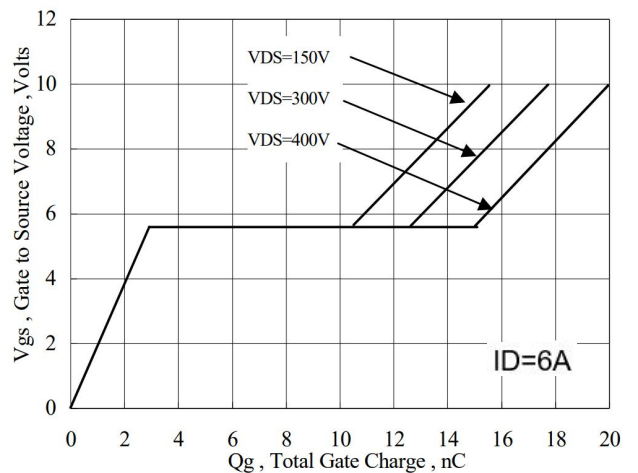


Figure 6. Typical Gate Charge vs. Vgs

TYPICAL CHARACTERISTICS(Cont.)

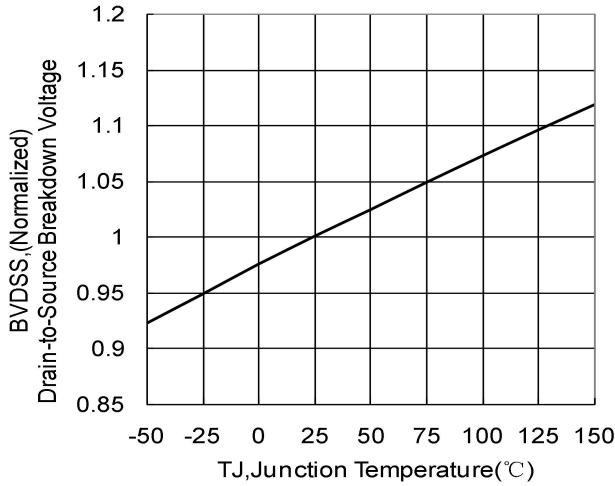


Figure 7. Bvdss Variation with Temperature

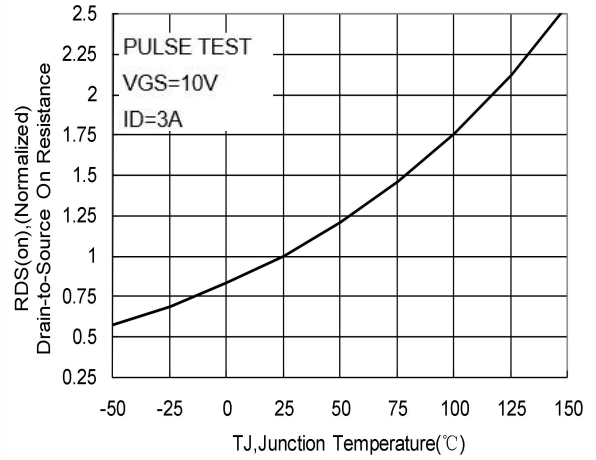


Figure 8. On-Resistance Variation with Temperature

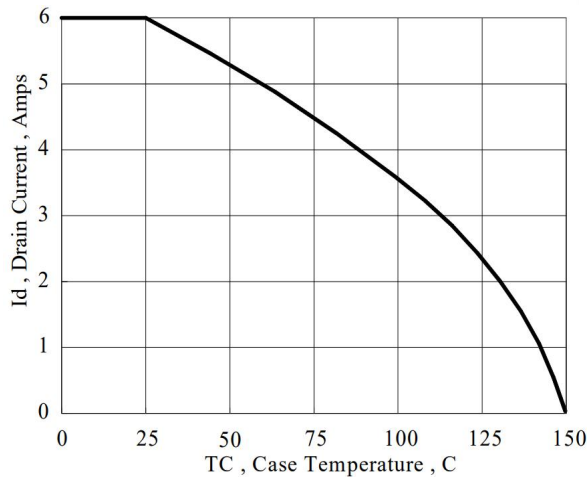
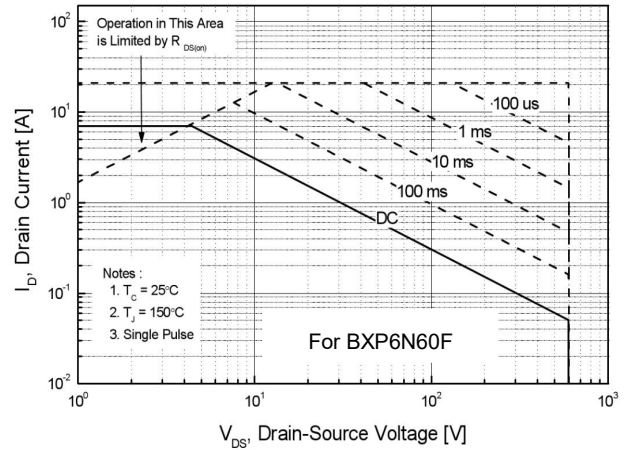
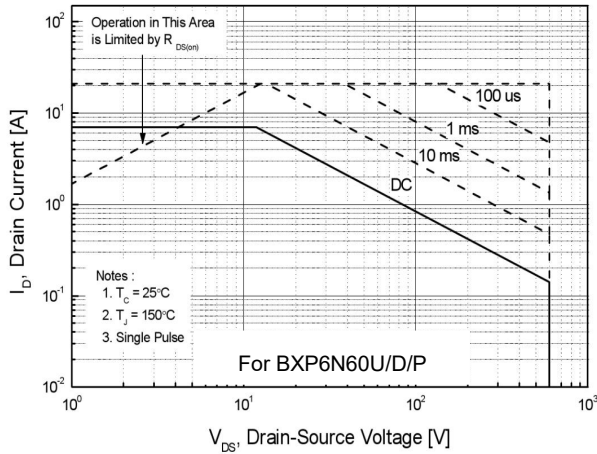
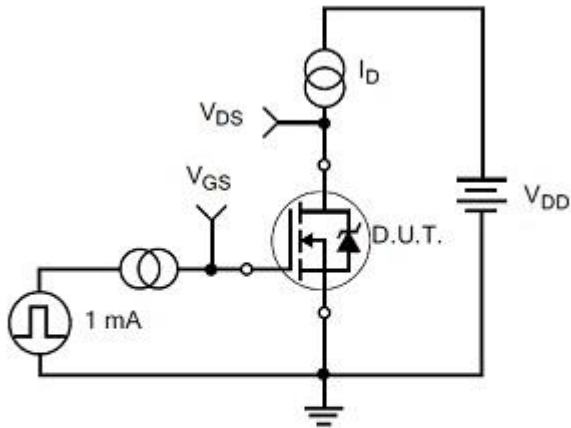
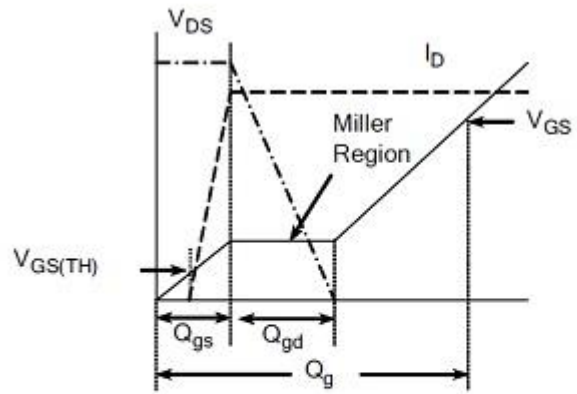


Figure 10. Maximum Continuous Drain Current vs Case Temperature

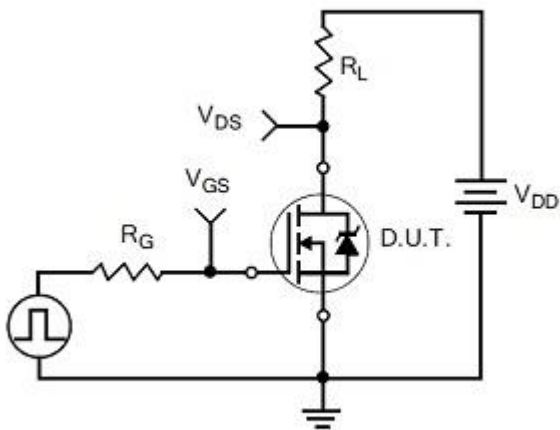
TEST CIRCUITS AND WAVEFORMS



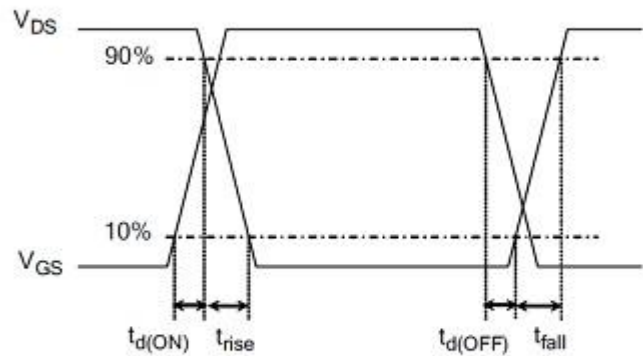
Gate Charge Test Circuit



Gate Charge Waveform

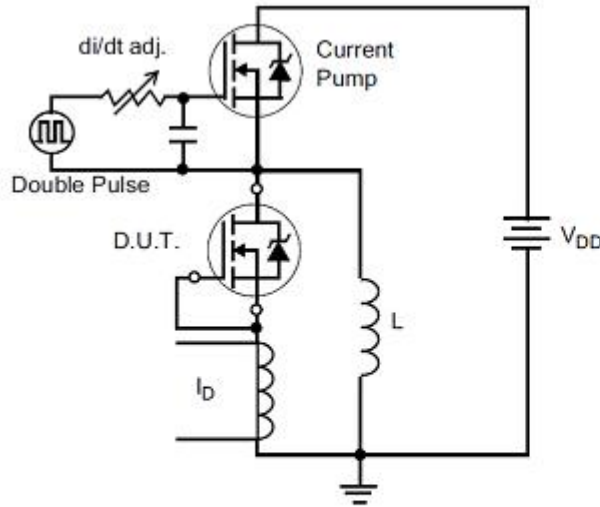


Resistive Switching Test Circuit

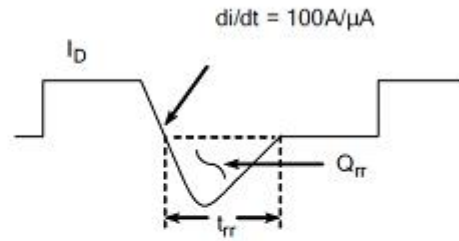


Resistive Switching Waveforms

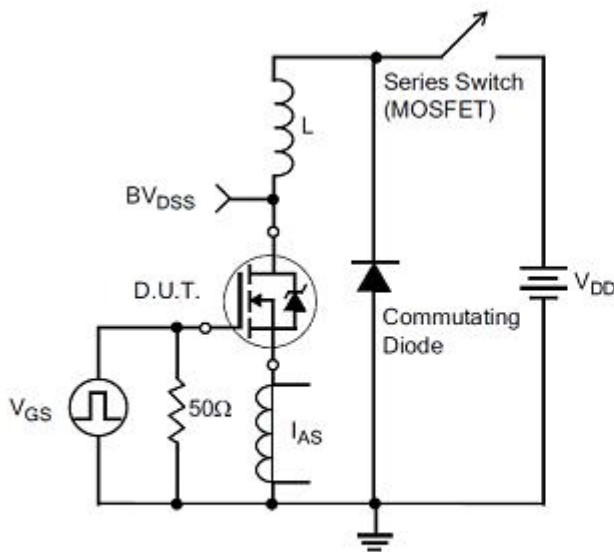
TEST CIRCUITS AND WAVEFORMS(Cont.)



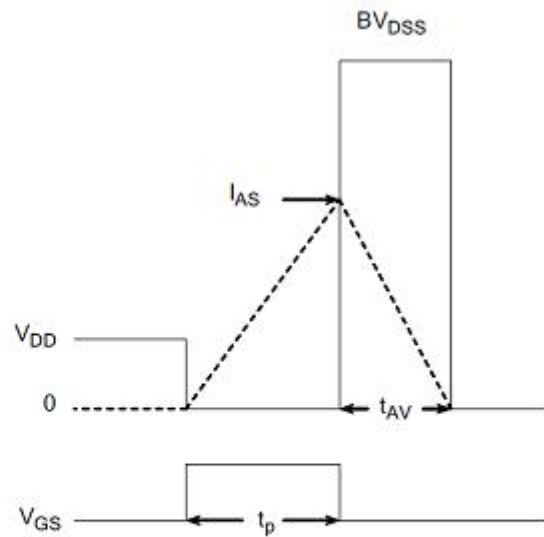
Diode Reverse Recovery Test Circuit



Diode Reverse Recovery Waveform



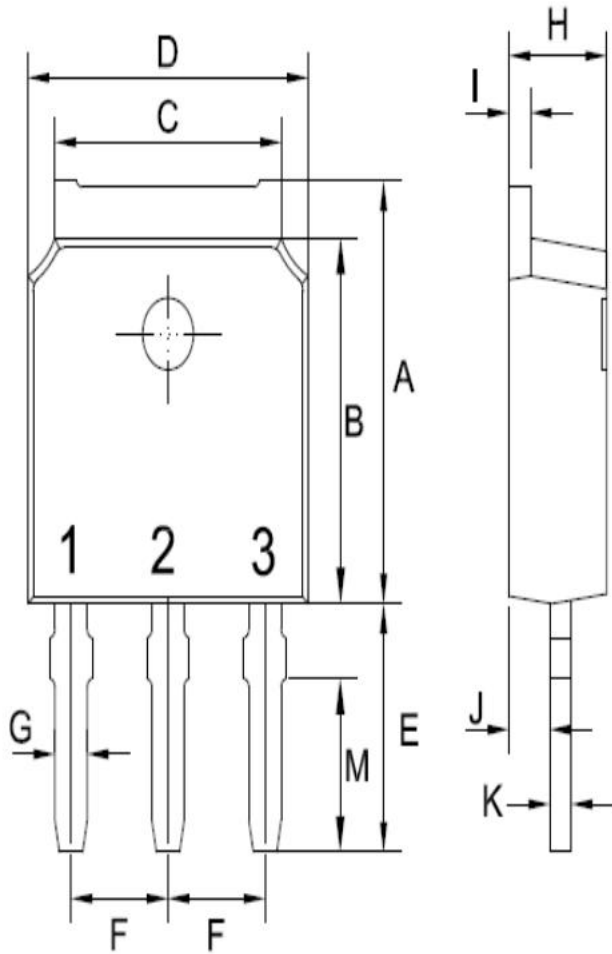
Unclamped Inductive Switching Test Circuit



$$E_{AS} = \frac{I_{AS}^2 L}{2}$$

Unclamped Inductive Switching Waveforms

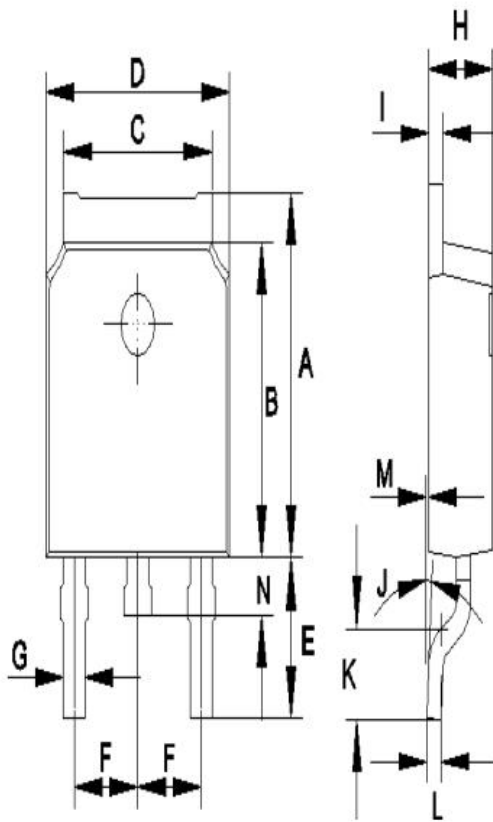
**TO-251 Package**



TO-251(IPAK)		
Unit:mm		
DIM	MIN	MAX
A	6.85	7.25
B	5.90	6.30
C	5.13	5.53
D	6.40	6.80
E	3.95	4.35
F	2.19	2.39
G	0.45	0.85
H	2.20	2.40
I	0.41	0.61
J	0.71	1.31
K	0.41	0.61
M	2.96	3.16



### TO-252 Package

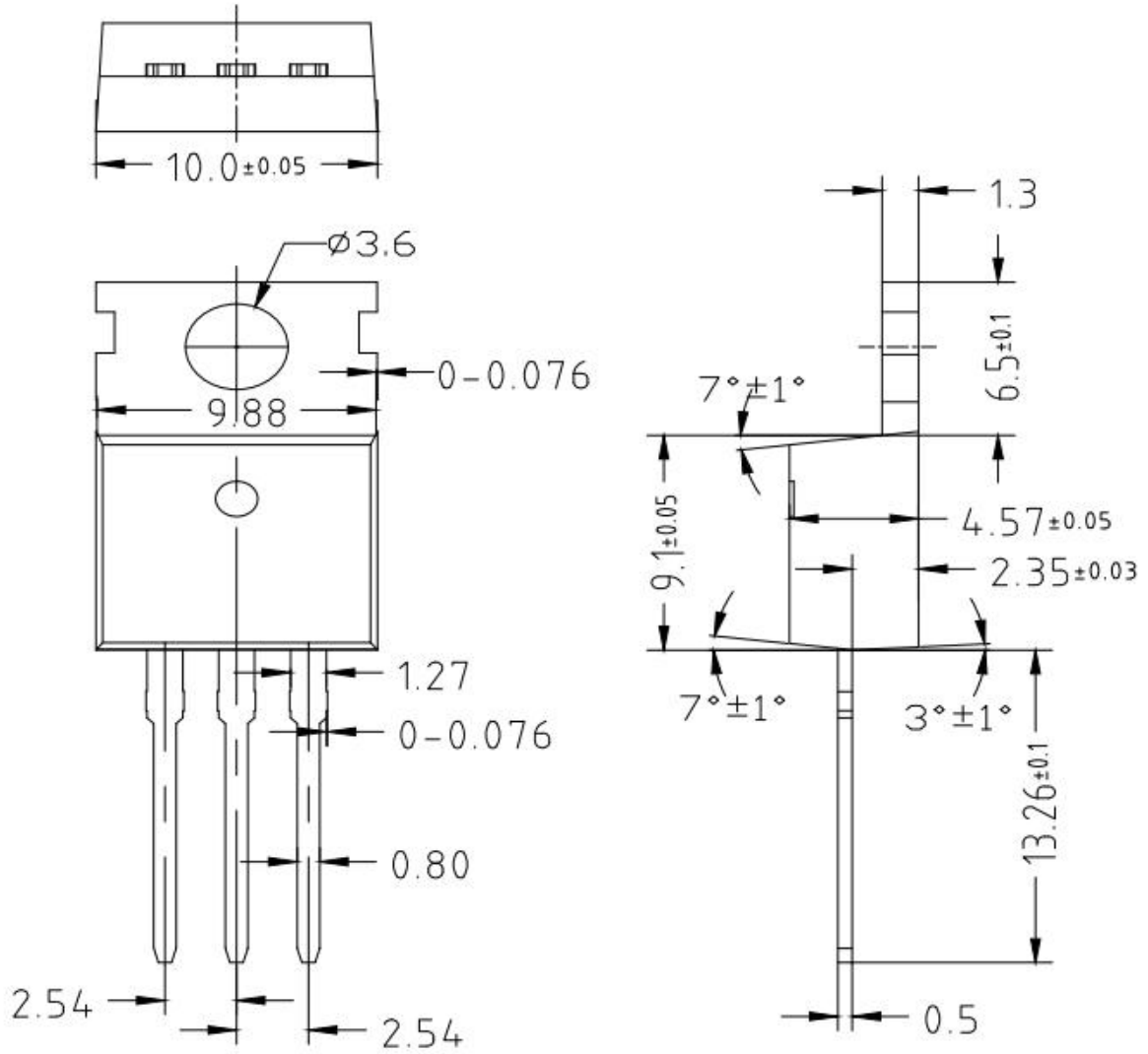


TO-252(DPAK)		
Unit: mm		
DIM	MIN	MAX
A	6.85	7.25
B	5.90	6.30
C	5.13	5.53
D	6.40	6.80
E	2.90	3.30
F	2.19	2.39
G	0.45	0.85
H	2.20	2.40
I	0.41	0.61
J	0°	8°
K	1.45	1.85
L	0.41	0.61
M	0.00	0.12
N	0.60	1.00



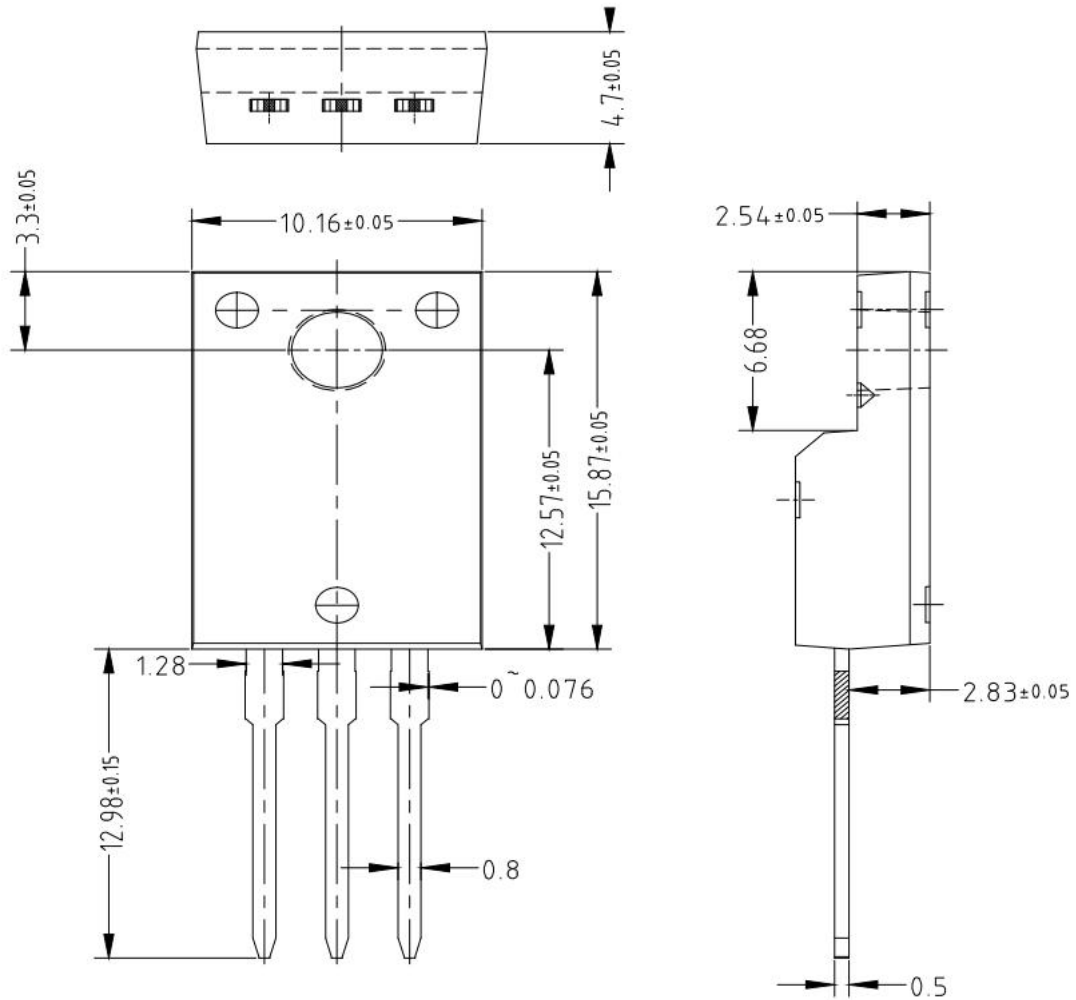
### TO-220 Package

Package Outline Dimensions (Units: mm)



### TO-220F Package

Package Outline Dimensions (Units: mm)



## Revision history

### Document revision history

Date	Revision	Changes
10-Jun-2021	1.0	First release
4-Jan-2022	1.1	Update parameter

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